MM54C42, MM74C42

BCD-to-Decimal Decoder

The MM54C42/MM74C42 one-of-ten decoder is a monolithic complementary MOS (CMOS) integrated circuit constructed with N- and P-channel enhancement transistors. This decoder produces a logical “0” at the output corresponding to a four bit binary input from zero to nine, and a logical “1” at the other outputs. For binary inputs from ten to fifteen all outputs are logical “1”.

Rochester Electronics Manufactured Components

Rochester branded components are manufactured using either die/wafers purchased from the original suppliers or Rochester wafers recreated from the original IP. All recreations are done with the approval of the OCM.

Parts are tested using original factory test programs or Rochester developed test solutions to guarantee product meets or exceeds the OCM data sheet.

Quality Overview

- ISO-9001
- AS9120 certification
- Qualified Manufacturers List (QML) MIL-PRF-38535
    - Class Q Military
    - Class V Space Level
- Qualified Suppliers List of Distributors (QSLD)
    - Rochester is a critical supplier to DLA and meets all industry and DLA standards.

Rochester Electronics, LLC is committed to supplying products that satisfy customer expectations for quality and are equal to those originally supplied by industry manufacturers.

The original manufacturer’s datasheet accompanying this document reflects the performance and specifications of the Rochester manufactured version of this device. Rochester Electronics guarantees the performance of its semiconductor products to the original OEM specifications. ‘Typical’ values are for reference purposes only. Certain minimum or maximum ratings may be based on product characterization, design, simulation, or sample testing.

National Semiconductor

March 1988

MM54C42/MM74C42 BCD-to-Decimal Decoder

General Description

The MM54C42/MM74C42 one-of-ten decoder is a monolithic complementary MOS (CMOS) integrated circuit constructed with N- and P-channel enhancement transistors. This decoder produces a logical "0" at the output corresponding to a four bit binary input from zero to nine, and a logical "1" at the other outputs. For binary inputs from ten to fifteen all outputs are logical "1".

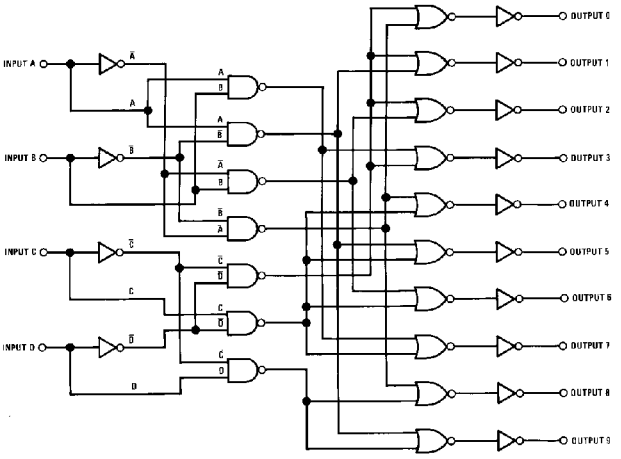
Features

- Supply voltage range — 3V to 15V
- Tenth power TTL compatible — drive 2 LPTTL loads
- High noise immunity — 0.45 V_{CC} (typ.)
- Low power — 50 nW (typ.)
- Medium speed operation — 10 MHz (typ.) with 10V V_{CC}

Applications

- Automotive
- Data terminals
- Instrumentation
- Medical electronics
- Alarm systems
- Industrial electronics
- Remote metering
- Computers

Schematic Diagram



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Truth Table

Inputs				Outputs									
D	C	B	A	0	1	2	3	4	5	6	7	8	9
0	0	0	0	0	1	1	1	1	1	1	1	1	1
0	0	0	1	1	0	1	1	1	1	1	1	1	1
0	0	1	0	1	1	0	1	1	1	1	1	1	1
0	0	1	1	1	1	1	0	1	1	1	1	1	1
0	1	0	0	1	1	1	1	0	1	1	1	1	1
0	1	0	1	1	1	1	1	1	0	1	1	1	1
0	1	1	0	1	1	1	1	1	1	0	1	1	1
0	1	1	1	1	1	1	1	1	1	1	0	1	1
1	0	0	0	1	1	1	1	1	1	1	1	0	1
1	0	0	1	1	1	1	1	1	1	1	1	1	0
1	0	1	0	1	1	1	1	1	1	1	1	1	1
1	0	1	1	1	1	1	1	1	1	1	1	1	1
1	1	0	0	1	1	1	1	1	1	1	1	1	1
1	1	0	1	1	1	1	1	1	1	1	1	1	1
1	1	1	0	1	1	1	1	1	1	1	1	1	1
1	1	1	1	1	1	1	1	1	1	1	1	1	1

RRD-B30M105/Printed in U. S. A.

Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Voltage at Any Pin (Note 1)	−0.3V to V_{CC} + 0.3V
Operating Temperature Range	
MM54C42	−55°C to +125°C
MM74C42	−40°C to +85°C
Storage Temperature Range	−65°C to +150°C
Power Dissipation (P_D)	
Dual-In-Line	700 mW
Small Outline	500 mW
Operating V_{CC} Range	3.0V to 15V
Absolute Maximum V_{CC}	18V
Lead Temperature (Soldering, 10 seconds)	260°C

DC Electrical Characteristics

Min/Max limits apply across temperature range unless otherwise noted

Symbol	Parameter	Conditions	Min	Typ	Max	Units
CMOS TO CMOS						
$V_{IN(1)}$	Logical "1" Input Voltage	V_{CC} = 5.0V	3.5			V
		V_{CC} = 10V	8.0			V
$V_{IN(0)}$	Logical "0" Input Voltage	V_{CC} = 5.0V			1.5	V
		V_{CC} = 10V			2.0	V
$V_{OUT(1)}$	Logical "1" Output Voltage	V_{CC} = 5.0V, I_O = −10 μA	4.5			V
		V_{CC} = 10V, I_O = −10 μA	9.0			V
$V_{OUT(0)}$	Logical "0" Output Voltage	V_{CC} = 5.0V, I_O = 10 μA			0.5	V
		V_{CC} = 10V, I_O = 10 μA			1.0	V
$I_{IN(1)}$	Logical "1" Input Current	V_{CC} = 15V, V_{IN} = 15V			1.0	μA
$I_{IN(0)}$	Logical "0" Input Current	V_{CC} = 15V, V_{IN} = 0V	−1.0			μA
I_{CC}	Supply Current	V_{CC} = 15V		0.05	300	μA
CMOS/LPTTL INTERFACE						
$V_{IN(1)}$	Logical "1" Input Voltage	54C, V_{CC} = 4.5V	V_{CC} − 1.5			V
		74C, V_{CC} = 4.75V	V_{CC} − 1.5			V
$V_{IN(0)}$	Logical "0" Input Voltage	54C, V_{CC} = 4.5V			0.8	V
		74C, V_{CC} = 4.75V			0.8	V
$V_{OUT(1)}$	Logical "1" Output Voltage	54C, V_{CC} = 4.5V, I_O = −360 μA	2.4			V
		74C, V_{CC} = 4.75V, I_O = −360 μA	2.4			V
$V_{OUT(0)}$	Logical "0" Output Voltage	54C, V_{CC} = 4.5V, I_O = 360 μA			0.4	V
		74C, V_{CC} = 4.75V, I_O = 360 μA			0.4	V
OUTPUT DRIVE (see 54C/74C Family Characteristics Data Sheet) T_A = 25°C (short circuit current)						
I_{SOURCE}	Output Source Current	V_{CC} = 5.0V, $V_{IN(0)}$ = 0V, V_{OUT} = 0V	−1.75			mA
I_{SOURCE}	Output Source Current	V_{CC} = 10V, $V_{IN(0)}$ = 0V, V_{OUT} = 0V	−8.0			mA
I_{SINK}	Output Sink Current	V_{CC} = 5.0V, $V_{IN(1)}$ = 5.0V, V_{OUT} = V_{CC}	1.75			mA
I_{SINK}	Output Sink Current	V_{CC} = 10V, $V_{IN(1)}$ = 10V, V_{OUT} = V_{CC}	8.0			mA

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.

AC Electrical Characteristics* $T_A = 25°C$, $C_L = 50$ pF, unless otherwise specified

Symbol	Parameter	Conditions	Min	Typ	Max	Units
t_{pd}	Propagation Delay Time to Logical "0" or "1"	$V_{CC} = 5.0V$		200	300	ns
		$V_{CC} = 10V$		90	140	ns
C_{IN}	Input Capacitance	(Note 2)		5		pF
C_{PD}	Power Dissipation Capacitance	(Note 3)		50		pF

*AC Parameters are guaranteed by DC correlated testing.

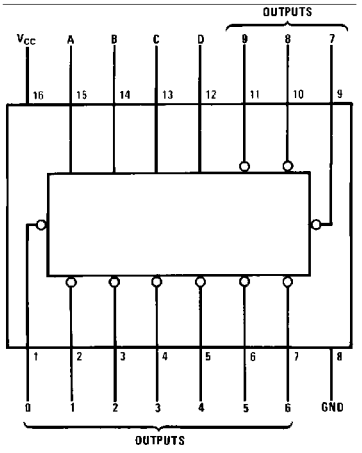
Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.

Note 2: Capacitance is guaranteed by periodic testing.

Note 3: C_{PD} determines the no load AC power consumption of any CMOS device. For complete explanation see 54C/74C Family Characteristics Application Note—AN-90.

Connection Diagram

Dual-In-Line Package



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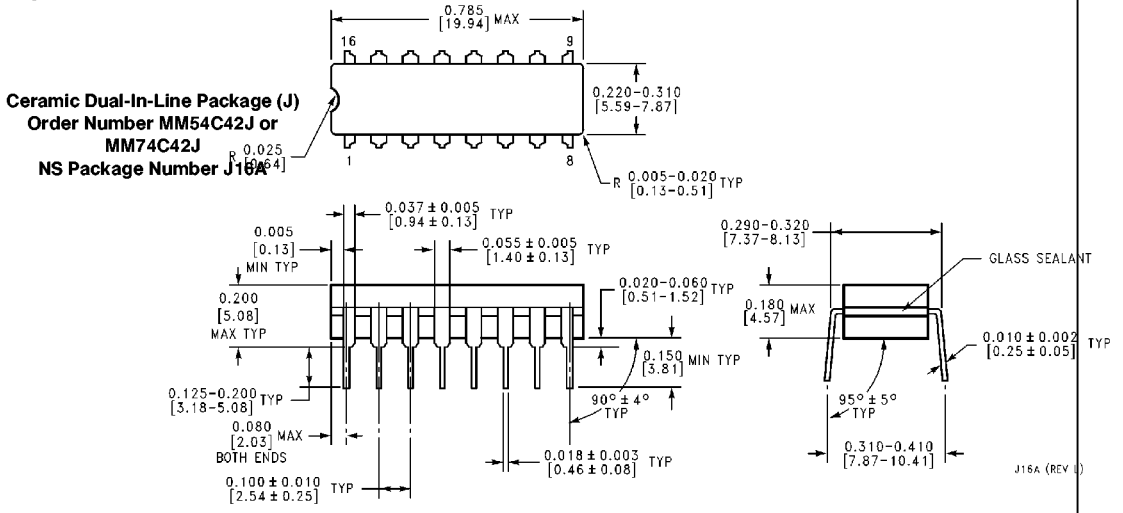
Top View

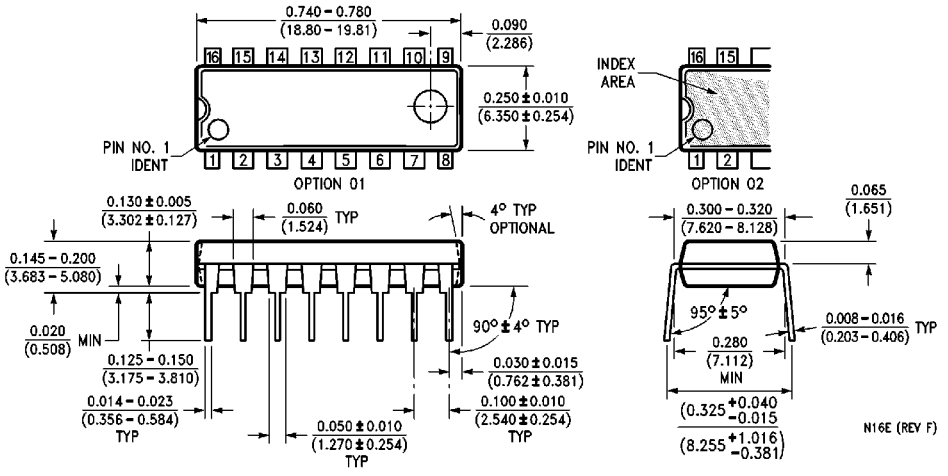
Order Number MM54C42 or MM74C42

Physical Dimensions inches (millimeters)

Ceramic Dual-In-Line Package (J)
Order Number MM54C42J or MM74C42J
NS Package Number J16A



Physical Dimensions inches (millimeters) (Continued)



Molded Dual-In-Line Package (N)
Order Number MM54C42N or MM74C42N
NS Package Number N16E

LIFE SUPPORT POLICY

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2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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